Improving the Rate Performance of Manganese Dioxide by Doping with Cu$^{2+}$, Co$^{2+}$ and Ni$^{2+}$ ions

You Yang$^1$, Xiaobing Huang$^2$, Yuqing Yang$^1$, Cailin Wu$^1$, Ben Lei$^1$, Qirong Peng$^1$, Guoping Wang$^1,*$

$^1$College of Chemical Engineering, University of South China, Hengyang 421001, China
$^2$College of Chemistry and Chemical Engineering, Hunan University of Arts and Science, Changde 415000, China
*E-mail: wgpcd@aliyun.com

Received: 1 December 2018 / Accepted: 28 January 2019 / Published: 10 March 2019

Metal-doped MnO$_2$ has been successfully synthesized via chemical precipitation method. Interestingly, doping can increase not only ion conductivity but also intrinsic electron conductivity. By doping, the particle size of MnO$_2$ decreases, relatively appropriate pore size distribution is obtained, and physically and chemically bound water content increases, all of which contribute to ion conductivity. Meanwhile, doping has induced some defects in MnO$_2$ crystal, increasing the hole concentration and then intrinsic electron conductivity. As the result, metal-doped MnO$_2$ displays better rate performance than the undoped. Especially, nickel-doped MnO$_2$ exhibits the best rate behavior. Even at 8 A g$^{-1}$, nickel-doped MnO$_2$ still has a specific capacitance as high as 234.0 F g$^{-1}$, larger than that of the undoped obtained at 1 A g$^{-1}$ (only 173.6 F g$^{-1}$). In conclusion, doping is a useful way for improving the rate performance of MnO$_2$.

Keywords: Manganese dioxide, Metal doping, Supercapacitor, Rate performance

1. INTRODUCTION

Serving as one kind of supercapacitor electrode materials, transition metal oxides can store energy not only through ion adsorption/desorption within electrochemical double-layer but also through fast and reversible redox reactions on the surface of electrode materials. As a result, they can provide a specific capacitance as much as 10-100 times higher than that of electronic double-layer capacitor electrode materials, and more and more researchers are focusing on this kind of material.

Among the transition metal oxides, ruthenium oxide has been extensively studied because of its exceptional properties such as metallic-type conductivity, good thermal stability, high specific energy and high rate performance [1]. However, its large commercialization has been blocked by its high cost,
high toxicity and low reserves. A significant effort has been put into finding cheaper and environmentally friendly materials. Since Lee and Grodenough [2] reported the electrochemical properties of manganese dioxide in 1999. Researchers are turning their attention to MnO₂ electrode material owing to its abundance in nature, low price, environmental friendliness and high theoretical specific capacity (1370 F g⁻¹ within the potential window of 0-0.8 V). Relative study on manganese oxide has extended from one-dimensional to three-dimensional nanostructure[3-6] and it has been considered as an alternative candidate electrode material for electrochemical supercapacitor. Unfortunately, MnO₂ usually suffers from low electrical and ion conductivity [7]. As the result, its specific capacitance often decreases dramatically with increasing the thickness of the electrode and potential scan rate, and the rate capability is far from the need of large power for supercapacitor. In attempt to promote its electrical conductivity, highly conductive additives are often introduced into the composite electrode. The common conductive additives involve active carbon [8], carbon nanotubes fibers [9], carbon nanotube (CNT) [10], graphene [11], polyaniline [12], polypyrrole[13], polythiophene [14]. For example, the composite of Mn oxide/CNT [15] could reach a specific capacitance of 415 F g⁻¹, because CNTs provided electronic conductive paths and formed a network of open mesopores. Without any doubt, the presence of conductive additives can form a three-dimensional conducting network and significantly improve the apparent electron conductivity of MnO₂ electrode. Nevertheless, with regard to its poor intrinsic electron conductivity and ion conductivity, it is beyond the reach of conductive additives. Consequently, the rate performance, which is a critical performance for supercapacitor, is still not satisfied. To achieve higher rate performance, it is necessary to further improve its intrinsic electron conductivity and ion conductivity.

Electrical properties are determined by crystal structure and the defect. It has been reported that the electrical conductivity of electrical insulator can be dramatically improved by changing stoichiometry or introducing dopants [16]. Through accommodating foreign substitutional ions with various valence and ionic radii, defects has been introduced into the crystal lattice, altering the conductivity by contributing electron or hole. For instance, defect cation can result in electron hole, increasing the valence state of corresponding positive ion and in turn the conductivity of the crystal. Doping technology has been widely applied to semiconductor field for optimizing their electrical properties. Bismuth [17], silver [18], iron [19] and cobalt [20] have been successfully doped into titanium oxide and cerium gadolinium oxide to change the density of electron states in the band gap of the semiconductor structure, giving rise to higher intrinsic conductivity of crystal. Only 0.05% Bi³⁺ can lead to a 2.67-fold increase in the conductivity of TiO₂ [17]. Generally, the doping effect may be much better if the radius of doping ion is closer to the radius of the metal ion substituted. Thus, here we chosen Cu²⁺ (0.073 nm), Co²⁺ (0.065 nm) and Ni²⁺ (0.069 nm) as the dopants for MnO₂ because of their similar radius to Mn⁴⁺ (0.065nm).

In this paper, manganese oxide was doped successfully with Cu²⁺, Co²⁺, Ni²⁺ and their effects on the electrochemical properties have been investigated by cyclic voltammetry (CV), galvanostatic charge-discharge (GCD) and electrochemical impedance spectra (EIS) in 0.5mol L⁻¹ Na₂SO₄ solution. The results demonstrate that metal doping can improve not only the ion conductivity but also the intrinsic electron conductivity of MnO₂ and then the rate capability. Especially, in the presence of nickel, MnO₂ are expected to show much better rate capability.
2. EXPERIMENT SECTION

2.1. Material synthesis

Manganese dioxide was doped by facile chemical precipitation method. The synthesis process typically involves three steps: (1) 3 mmol manganese sulfate monohydrate and 0.45 mmol nickel nitrate hexahydrate were dissolved in 40 ml deionized water, and then 4 mmol potassium permanganate was slowly added into the above mixture solution. (2) The reaction lasted for 12 hrs at room temperature. (3) After filtered, the precipitation was washed with deionized water for several times. The samples obtained were dried at 80°C for 8 hrs. The product prepared was marked as MnO$_2$-Ni. Such a process was also adopted to prepare the un-doped, cobalt-doped and copper-doped manganese dioxide, which were marked as MnO$_2$-undoped, MnO$_2$-Co, MnO$_2$-Cu, respectively.

2.2 Materials characterization

The crystal structures of manganese dioxide were characterized using MAX2200 X-ray diffractometer. The scanning wavelength was 0.02° and the diffraction angle ranged from 5 to 90°. It was operated at 40 kv using Cu Kα radiation at a scanning rate of 5° min$^{-1}$. The morphologies and sizes of the as-prepared samples were observed using scanning electron microscopy (SEM, Zeiss Super55 operated at 5kV). The specific surface areas of the materials were tested by Beijing 3H-2000PS2 volumetric adsorption analyzer utilizing nitrogen as adsorption/desorption gas at 77.3 K, and the corresponding values were determined according to brunnauer emmett teller (BET) method. The pore size distribution was analyzed with the Barrett-Jouner-Halenda (BJH) method. Fourier transform infrared spectrometer (FT-IR) were obtained with Bruker Prestige-21 by dispersing the sample in KBr and pressing it into transparent pellets. The surface element analysis of the samples were performed by energy dispersive X-ray spectrometry (EDS, Oxford X-Max 20).

2.3 Preparation of electrodes and electrochemical characterization

The electrochemical performance was evaluated using CH660E electrochemical working station with a three-electrode system. Platinum electrode served as the counter electrode, saturated calomel electrode as the reference electrode and glassy carbon electrode as the working electrode. The working electrode was prepared as follows: Firstly, under ultrasonication, carbon nanotubes (1.5 mg) and manganese oxide (9.0 mg) were dispersed in 5.0 ml isopropanol for 30 min to form a homogeneous solution. Then, 5.0 μL of the above homogeneous solution was pipetted gradually onto the surface of a glassy carbon electrode. After naturally drying, the surface of glass carbon electrode was covered with 5 μL of the dilated Nafion® solution (0.1% wt%, Aldrich) to form a uniform electrode protection layer. The samples’ electrochemical performances were characterized by CV within a potential window ranging from 0 to 0.8 V at 5 mV s$^{-1}$ potential scanning rate. The GCD curves were measured at the scale ranging from 1 to 8 A g$^{-1}$. The EIS was measured within a frequency range of 1~100000 Hz. The electrolyte solution used in the electrochemical performance test experiments was 0.5 mol L$^{-1}$ Na$_2$SO$_4$. 
solution. The specific capacitance of the electrode materials was estimated from the charge-discharge curves according to the equation:

\[ C_{sp} = \frac{I \times \Delta t}{\Delta V \times m} \]

where \( C_{sp} \) was the specific capacitance, \( I \) was the charge-discharge current (A), \( \Delta t \) was the discharge time (s), \( \Delta V \) was the charge-discharge potential window (V), and \( m \) was the mass of the active material (g).

3. RESULTS AND DISCUSSION

Fig. 1 depicts the XRD patterns of the metal ion-doped and un-doped birnessite manganese dioxide. No sharp diffraction peaks appear in the four samples, suggesting their poorly crystallized structure. Meanwhile, all the XRD patterns have two identical broader diffraction peaks at 37.3° and 66.2°, which are well indexed to (1, 1, 1) and (0, 0, 5) planes of JCPDS No.80-1098, respectively. This indicates that the samples can be categorized into birnessite manganese dioxide, agreeing well with the manganese dioxide obtained by Kim [26]. In addition, compared with undoped MnO₂, the three doped oxides show no obvious impurity peaks, implying the forming of solid solution in the doped samples.

![Figure 1. XRD patterns of MnO₂-undoped, MnO₂-Ni, MnO₂-Co and MnO₂-Cu](image)

Fig. 2 shows the SEM images of the four manganese dioxides. It can be seen that the four samples show similar morphology. Nevertheless, the undoped MnO₂ shows an average particle size of about 400 nm, much larger than that of doped MnO₂. Particularly, MnO₂ doped with Ni²⁺ or Co²⁺ presents an average particle size no more than 200 nm, only about one half of the un-doped MnO₂. Based on the phenomenon, it can be concluded that doping agents may decrease the surface energy of MnO₂ seeds and preventing the seed from further growing [32]. In other references, similar effect on morphology and particle size of oxides has been reported for ion doping [27,33], but the variation of the material particles after doping is more obvious in this paper.
EDS was used to identify the element composition of the composite. As shown in Fig. 3, four samples show the presence of potassium ions. It has been reported that potassium ions may enter manganese vacancies of manganese oxygen octahedral to make the crystal more stable [21]. Meanwhile, the peaks of nickel, cobalt and copper are observed in the corresponding samples, indicating that nickel, cobalt and copper ions may have entered into manganese dioxide crystal lattice. According to the collected data from Fig. 3, the rate of X/Mn (X=Ni,Co,Cu) is determined to be 0.0176, 0.0459 and 0.0341, respectively.
The specific surface was determined by Brunauer-Emmett-Teller using nitrogen as adsorption gas at 77.3 K. As shown in Fig. 4a, at very low partial pressure, all the four isotherms increase abruptly. Especially, for Ni$^{2+}$-doped MnO$_2$, its micropore volume can be as four times as that of the un-doped, implying its largest volume of micropores. With the increase of partial pressure ($P/P_0>$0.45), the metal-doped MnO$_2$ displays some hysteresis in the adsorption isotherms, indicating the existence of mainly mesopores (>2.0 nm) in those samples [39]. Among them, Ni$^{2+}$-doped MnO$_2$ shows more pronounced hysteresis, indicating its larger amount of mesopores. However, in the MnO$_2$-undoped, there is almost no hysteresis. This suggests that the amount of mesopores in it is very small. When the partial pressure approximates to unity, no plateau (namely, saturation) is observed in all the four samples because of the multilayer formation. This observation provides the evidence for the presence of macropore, which originates from the large aggregates of particles. Here, it must be pointed out that the rise in the isotherm of MnO$_2$-Co is the steepest, which suggests the highest volume of macropores. The above results agree well with the BJH pore-size distribution. From Fig. 4b, it can be seen that metal–doping has led to some more micro– and meso–pore volume. Among them, MnO$_2$-Ni shows the largest micropore and mesopore volume than the others, particularly at the pore diameter of about 3.9 nm. These results may account for the highest specific surface area of MnO$_2$-Ni. Its calculated specific surface area reaches as high as 140.7 m$^2$ g$^{-1}$, much higher than that of MnO$_2$-Co (67.2 m$^2$ g$^{-1}$), MnO$_2$-Cu (68.1 m$^2$ g$^{-1}$) and the MnO$_2$-undoped (only 35.0 m$^2$ g$^{-1}$). Compared with the undoped manganese dioxides (15-68 m$^2$ g$^{-1}$) prepared by Nayak [34], our doped manganese dioxides show much larger specific surface area. The average pore sizes calculated by BJH mode from the pore size distribution are 5.1, 5.8, 11.8 and 7.1 nm for MnO$_2$-undoped, MnO$_2$-Ni, MnO$_2$-Co and MnO$_2$-Cu, respectively.

![Figure 4.](image)

The FT-IR spectra of MnO$_2$-undoped, MnO$_2$-Ni, MnO$_2$-Co and MnO$_2$-Cu are presented in Fig. 5. The absorption bands at around 3390 and 1629 cm$^{-1}$ correspond to O-H stretching vibration absorption and bending vibrations absorption of water, respectively. According to Lambert-Beer law, the stronger the absorbance is, the higher the corresponding component concentration. Apparently, the above two peaks in the doped MnO$_2$ are much stronger than in the MnO$_2$-undoped. This phenomenon points to the
fact that water content in the doped MnO$_2$ is higher. This may be because the doping metal ions make MnO$_2$ easily form hydrates [22]. Similarly, Chen [35] has reported that iron doping can result in higher content of crystal water, which is line with our results. In addition, all the samples show a strong characteristic peak at around 534 cm$^{-1}$, which can be assigned to Mn-O stretching vibrations [36]. However, the characteristic peaks of nickel, cobalt and copper oxides are not obvious in the corresponding compound except that the peak at about 534 cm$^{-1}$ extends to some larger wavenumber. Two factors may contribute to such a result. One is the amount of doping elements is in trace. The other is that doping elements can substitute for manganese in the crystal due to their similar size and their characteristic peak are very close to that of manganese oxide. Thus, they overlaid to form broad peaks.

![FT-IR patterns of MnO$_2$-undoped, MnO$_2$-Ni, MnO$_2$-Co and MnO$_2$-Cu](image)

**Figure 5.** The FT-IR patterns of MnO$_2$-undoped, MnO$_2$-Ni, MnO$_2$-Co and MnO$_2$-Cu

The electrochemical properties were investigated by CV, GCD and EIS. Fig. 6a displays the typical CV curves of the four samples at 5 mV s$^{-1}$. The curves of MnO$_2$-undoped and MnO$_2$-Ni are quasi-rectangular and symmetrical, indicating their ideal electrical double-layer capacitive behavior. Generally, metal–doped MnO$_2$ shows larger integrated area than the MnO$_2$-undoped, implying their larger specific capacitance. This may be attributed to their higher specific surface, which can expose more electrochemical active points for the storage of electrostatic charge at the double-layer interface. These consistent with the charge/discharge curves presented in Fig. 6b. In this figure, MnO$_2$-undoped and MnO$_2$-Ni show a charge/discharge profile with quasi–triangular mirror-like symmetrical distribution, suggesting they store charges mainly in an electrochemical double-layer. Meanwhile, metal–doped MnO$_2$ spends longer charging–discharging time than the un-doped. It is worthy to note that the profiles of MnO$_2$-Co and MnO$_2$-Cu deviate far from triangle and their charging time is much longer than their discharging time. From these, it can be concluded that some irreversible processes may take place in MnO$_2$-Co and MnO$_2$-Cu. Based on GCD curves, the discharge specific capacitances of MnO$_2$-undoped, MnO$_2$-Ni, MnO$_2$-Co and MnO$_2$-Cu are calculated as 172.6, 335.1, 412.3 and 435.5 F g$^{-1}$ at 1 A g$^{-1}$, respectively.
Whether or not MnO$_2$ is doped, the discharge specific capacitance decreases with the increase of current density (Fig. 6c). However, metal–doped MnO$_2$ presents much larger specific capacitance than the un–doped no matter what the current density is. Even at 8 A g$^{-1}$, their specific capacitance is still larger than that of the un–doped obtained at 1 A g$^{-1}$. Particularly, Ni–doped MnO$_2$ exhibits the best rate performance. At the current density of 8 A g$^{-1}$, its discharge specific capacitance can reach 234.0 F g$^{-1}$, maintaining about 70% of its specific capacitance obtained at 1 A g$^{-1}$.

Table 1 compares the obtained electrochemical performance of our MnO$_2$-based materials with those results reported in references. Although some results are very close to reference, the experiment conditions are quite different. Since this paper focuses on the rate performance, the scan rate or current density generally is higher than those of most references, and some higher specific capacitance has been achieved compared with those results in references [24-27]. Although sodium-doped manganese oxide has a rate performance of 75.4% (at scan rate of 10 mV s$^{-1}$ compared with the specific capacitance at a scan rate of 1 mV s$^{-1}$). This improved performances originate with hierarchical pore structure and amorphous structure [40].

### Table 1. Comparison of Cs with other MnO$_2$-based electrodes

<table>
<thead>
<tr>
<th>Electrode Materials</th>
<th>Cs (F/g)</th>
<th>Scan rate or current density</th>
<th>Electrolyte</th>
<th>References</th>
</tr>
</thead>
<tbody>
<tr>
<td>MnO$_2$-B</td>
<td>269.0 F/g</td>
<td>50 mV S$^{-1}$</td>
<td>0.5M Na$_2$SO$_4$</td>
<td>24</td>
</tr>
<tr>
<td>MnO$_2$-Ag</td>
<td>770 F/g</td>
<td>2 mV S$^{-1}$</td>
<td>0.5M Na$_2$SO$_4$</td>
<td>25</td>
</tr>
<tr>
<td>MnO$_2$-Co</td>
<td>415 F/g</td>
<td>0.2 A g$^{-1}$</td>
<td>1M Na$_2$SO$_4$</td>
<td>26</td>
</tr>
<tr>
<td>MnO$_2$-Al</td>
<td>64.3 F/g</td>
<td>2 mV S$^{-1}$</td>
<td>0.1M Na$_2$SO$_4$</td>
<td>27</td>
</tr>
<tr>
<td>MnO$_2$/AC</td>
<td>375 F/g</td>
<td>0.1 A g$^{-1}$</td>
<td>1M Na$_2$SO$_4$</td>
<td>28</td>
</tr>
<tr>
<td>MnO$_2$/CNF</td>
<td>238 F/g</td>
<td>0.1 A g$^{-1}$</td>
<td>1M Na$_2$SO$_4$</td>
<td>28</td>
</tr>
<tr>
<td>MnO$_2$/CNT</td>
<td>349 F/g</td>
<td>0.1 A g$^{-1}$</td>
<td>1M Na$_2$SO$_4$</td>
<td>28</td>
</tr>
<tr>
<td>Sn@rGo-MnO$_2$</td>
<td>460.9 F/g</td>
<td>20 mV S$^{-1}$</td>
<td>1M Na$_2$SO$_4$</td>
<td>11</td>
</tr>
<tr>
<td>La-MnO$_2$(1:9)/MWCNTS</td>
<td>130 F/g</td>
<td>2 mV S$^{-1}$</td>
<td>0.1M Na$_2$SO$_4$</td>
<td>29</td>
</tr>
<tr>
<td>MnO$_2$/MWNT</td>
<td>285.1 F/g</td>
<td>1.0 A g$^{-1}$</td>
<td>1M Na$_2$SO$_4$</td>
<td>30</td>
</tr>
<tr>
<td>MnO$_2$/NG</td>
<td>302 F/g</td>
<td>1.0 A g$^{-1}$</td>
<td>1M Na$_2$SO$_4$</td>
<td>31</td>
</tr>
<tr>
<td>MnO$_2$/Ni</td>
<td>335.1 F/g</td>
<td>1.0 A g$^{-1}$</td>
<td>0.5M Na$_2$SO$_4$</td>
<td>This work</td>
</tr>
<tr>
<td>MnO$_2$-Co</td>
<td>412.3 F/g</td>
<td>1.0 A g$^{-1}$</td>
<td>0.5M Na$_2$SO$_4$</td>
<td>This work</td>
</tr>
<tr>
<td>MnO$_2$-Cu</td>
<td>435.5 F/g</td>
<td>1.0 A g$^{-1}$</td>
<td>0.5M Na$_2$SO$_4$</td>
<td>This work</td>
</tr>
</tbody>
</table>

**ABBREVIATIONS:**

The reasons for the better rate performance of metal–doped MnO₂ may involve: (1) Appropriate pore size distribution and particle size. Metal–doping has resulted in more micro– and meso–pore, especially MnO₂-Ni possesses the most micropore and mesopore. Large amount of micropores can dramatically improve specific surface area and then expose more active sites, increasing the specific capacitance [37]. Appropriate mesopores can facilitate the storage and transportation of electrolyte within electrode material, making electrolyte's entry into the pores easy and decreasing ion diffusion resistance and increasing the rate performance.

![Figure 6. (a) CV curves of MnO₂-undoped, MnO₂-Ni, MnO₂-Co and MnO₂-Cu at a scan rate of 5mV s⁻¹. (b) GCD of MnO₂-undoped, MnO₂-Ni, MnO₂-Co and MnO₂-Cu at current density of 1 A g⁻¹. (c) Corresponding specific capacitance at different current density. (d) EIS of MnO₂-undoped, MnO₂-Ni, MnO₂-Co and MnO₂-Cu](image)

Besides, for metal–doped MnO₂, their smaller particle size can also shorten the transportation distance of ions and decrease ion diffusion resistance [38]. (2) Higher water content. It is believed that physically and chemically bound water is expected to improve the transportation of electrolyte ions inside the electrode layer [23]. Therefore, the higher water content in metal–doped MnO₂ may result in better ion conductivity. Fast ionic conduction can weaken polarization of the electrode and then heighten rate performance. The EIS plots have further offered the convinced evidence for the higher ionic conductivity of metal–doped MnO₂. As shown in Fig. 6d, all the slopes of their straight lines at low frequency region are higher than that of the MnO₂-undoped. The higher the slope of straight line is, the higher the diffusion rate of electrolyte ions. (3) Higher electron conductivity. The semicircle of EIS plot at high frequency region represents the resistance of charge transfer in material. Smaller semicircle
diameter indicates the charge-transfer resistance is lower. From Fig. 6d, it can be seen that metal–doped MnO$_2$ has a smaller semicircle in the high frequency region, suggesting their higher electron conductivity. The calculated charge-transfer resistances are 687.5, 133.4, 145.7, 191.0 $\Omega$ for MnO$_2$-undoped, MnO$_2$-Ni, MnO$_2$-Co and MnO$_2$-Cu, respectively. The decrease in charge-transfer resistances of metal–doped MnO$_2$ may originate from the increase of hole concentration. Since the valence state of doping metal ion is lower than that of manganese ion, the doping may induce vacancies in the cation, that is, surplus negative ions in the crystal. To keep the electron neutrality in the substitutional sites, some of the metal cations are oxidized to higher valence state. Similar to doping metal in cerium gadolinium oxide [20], Co/Ni may present in a mixing state of Co$^{2+}$/Co$^{3+}$ or Ni$^{2+}$/Ni$^{3+}$, and parts of Mn$^{4+}$ are oxidized to higher valence state in MnO$_2$-Cu crystal, resulting in a contribution to electronic conduction. On the basis of the above described, doping may create traps for holes of MnO$_2$ and increases the hole concentration, giving rise to higher conductivity.

4. CONCLUSIONS

Metal-doped MnO$_2$ has been successfully synthesized and their electrochemical properties have been investigated. Although doping doesn't influence the crystal structure, it can prevent the seed from further growing, resulting in small particle size. Meanwhile, more micro–pores, meso–pores and specific surface area are found in metal–doped MnO$_2$, especially in MnO$_2$-Ni. In addition, metal–doped MnO$_2$ contains larger amount of water than the MnO$_2$-undoped. Their small particle size, appropriate pore size distribution and higher water content can lead to better ion conductivity. These are all beneficial for improving rate performance. Moreover, doping has induced some defects in crystal. Because of the defects, some metal ions exist in a mixing valence state in the crystal, and the hole concentration increases. As the result, metal–doped MnO$_2$ displays much larger rate specific capacitance than the MnO$_2$-undoped. Especially, nickel–doped MnO$_2$ exhibits the best rate capacity. Even at 8 A g$^{-1}$, MnO$_2$-Ni still shows much larger specific capacitance than that of the MnO$_2$-undoped obtained at 1 A g$^{-1}$. In conclusion, doping is a useful way for improving the ion and electron conductivity of MnO$_2$, and then the rate performance.

ACKNOWLEDGMENTS

This work was supported by the Natural Science Foundation of Hunan Province, China (grant number 2019JJJ60031), the Research Foundation of Education Bureau of Hunan Province, China (grant number 15B200), the Natural Science Foundation of Hunan Province, China (grant number 2016JJ3105) and the Postgraduate Science Foundation of University of south china (grant number 2018KYY047).

References